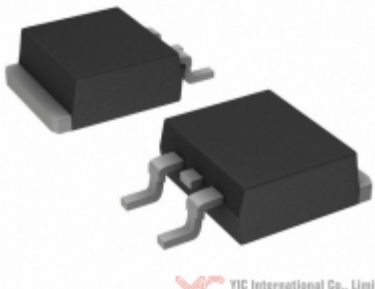

	<h2 style="color: #E67E22;">FQB630TM</h2>
	Hersteller-Teilenummer: FQB630TM
	Hersteller / Marke: Fairchild/ON Semiconductor
	Teil der Beschreibung: MOSFET N-CH 200V 9A D2PAK
	Datenblätter:  FQB630TM.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 5000 pcs Stock Available.
Liefern von: Hong Kong	
Versandweg: DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQB630TM
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 200V 9A D2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	5000 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D ² PAK (TO-263AB)
Verlustleistung (max)	3.13W (Ta), 78W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	200V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	9A (Tc)
Rds On (Max) @ Id, Vgs	400 mOhm @ 4.5A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	25nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	550pF @ 25V
Verpackung	Tape & Reel (TR)





























FQB630TM ist neu im Original, Suche FQB630TM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB630TM Fairchild/ON Semiconductor mit Garantie und Vertrauen.
Anfrage FQB630TM: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQB630TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 9A D2PAK</p>	 <p>FQB6N15TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 150V 6.4A D2PAK</p>	 <p>FQB60N03LTM FSC FSC TO-263</p>	 <p>FQB5P20TMX Fairchild/ON Semiconductor FQB5P20TMX FAIRCHILD</p>
 <p>FQB60N03L FSC FSC TO-263</p>	 <p>FQB65N06TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 65A D2PAK</p>	 <p>FQB6N15TM Fairchild/ON Semiconductor MOSFET N-CH 150V 6.4A D2PAK</p>	 <p>FQB65N06TM Fairchild/ON Semiconductor MOSFET N-CH 60V 65A D2PAK</p>

heiße Teile

Mehr

 FQB50N06LTM	 FQB50N06LTM	 FQB50N06M	 FQB50N06TM	 FQB50N06TM
 FQB50N06TM-NL	 FQB55N06TM	 FQB55N06TM	 FQB55N10	 FQB55N10TM
 FQB55N10TM	 FQB5N20L	 FQB5N30TM	 FQB5N30TM	 FQB5N50C
 FQB5N50CF	 FQB5N50CTM	 FQB5N50CTM	 FQB5N60CTM	 FQB5N60CTM
 FQB5N90TM	 FQB5N90TM	 FQB5P10TM	 FQB5P10TM	 FQB630TM
 FQB65N06	 FQB65N06TM	 FQB65N06TM	 FQB6N40C	 FQB6N40CF
 FQB6N40CTM	 FQB6N40CTM	 FQB6N50TM	 FQB6N50TM	 FQB6N60C
 FQB6N60CTM	 FQB6N60CTM	 FQB6N60TM	 FQB6N60TM	 FQB6N70TM
 FQB6N70TM	 FQB6N90TM	 FQB6N90TM_AM002	 FQB6N90TM_AM002	 FQB7042FB
 FQB7045FB	 FQB70N03	 FQB70N06	 FQB70N08	 FQB70N10TM

Contact us: Info@Y-IC.com

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